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Ultra-Bright Photocathode Physics Study and Design

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ERL09, Cornell U.

June 8-12, 2009

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Ultra-Bright Photocathode Physics Study and Design

- Fundamental cathode emission properties determine lower bound on achievable electron source emittance
- Intrinsic emittance depends on:
 - Emission momentum distribution
 - Surface roughness, nonuniformity
 - Surface impurities (e.g., oxide layers)
 - Grain boundaries
 - Laser profile, energy, polarization
- Angle-resolved photoemission spectroscopy (ARPES), an important tool in surface science, is also promising as a tool to characterize photocathodes*

* D. Sertore et al., Proc. 2004 EPAC; W. Wan, CHBB Mini-workshop, DESY Zeuthen (2008).



E.g., see Fig 6. in A. Damascelli, Physica Scripta T109, 61 (2004).

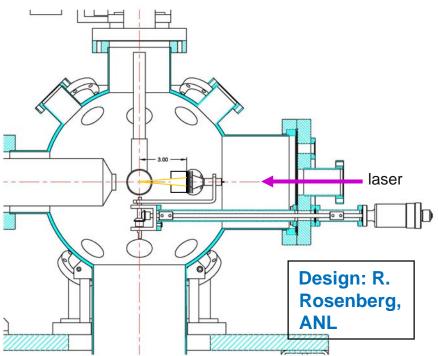
Basic ARPES geometry

Photocathode Surface Lab



- Also available:
 - Heat/cool sample
 - XPS to study surface chemistry (dual-anode AI, Mg source)
 - Scanning EM (on 2nd chamber)
- * K. Harkay et al., Proc. 2009 PAC (MO6RFP045)

- Existing UHV surface analysis chamber being upgraded to add UV ARPES *
 - Nd:YAG laser, 3-ns pulse (1064, 540, 355, 266 nm); UV flash lamp (1-µs), spectrometer
 - MCP TOF electron detector





Photocathode R&D

- Plan to start with existing cathodes (Cu, Cs₂Te*, diamond**); no facilities for *in-situ* cesiation (GaAs)
- UV ARPES chamber assembly underway; first measurements this year. Opportunity to compare intrinsic emittance results with
 - BNL, PITZ (msr'd in injector)
 - INFN, LBNL (ARPES labs)
 - others
- Preliminary theoretical calculations underway; suggest a design method for ultra-high-brightness cathodes
- Novel material designs that predict small emittance to be investigated experimentally
- Procurement or fabrication of novel cathodes: Argonne Materials Science Division (ALD), APS X-Ray Science Division, others

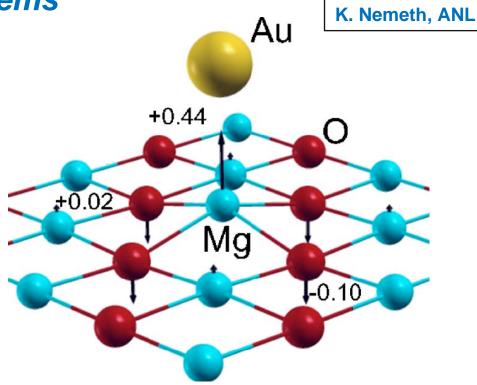
* Z. Yusof, http://www.hep.anl.gov/eyurtsev/psec

** J. Smedley, T. Rao, private discussion at ERL09



Preliminary ideas for low-transverse-emittance cathodes from surface catalysis systems

1. Analog of negative electron-affinity (NEA) cathode: Au on thin MgO layer over Ag(100) *



* J. Chem. Phys. 127, 144713 (2007)].

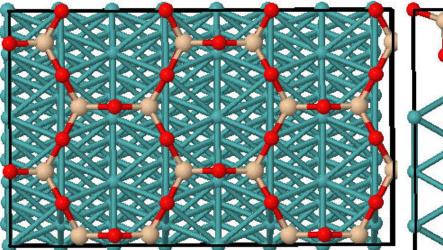
- Thin layer of MgO over Ag(100) dramatically reduces the work function of the Ag(100) surface
- System potentially useful as an analog of NEA cathodes
- NEA given by negative charge of Au atom (or other metal clusters) deposited on thin layer

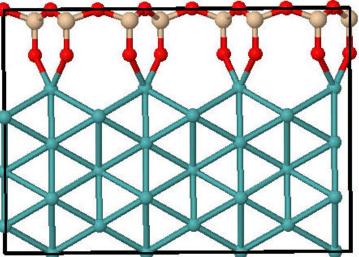


Preliminary ideas (cont)

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2. SiO₂ monolayer on Mo(112) surface *





See Fig. 1A in Ulrich et al.

STM images of Pd embedded in the SiO₂ monolayer (left), and Au atoms anchored to the embedded Pd atoms (right) Potential substitute for dispenser cathodes when Cs put into SiO2 honeycomb. Surface bands suggest small emittance.

See Fig. 1C in Ulrich et al.

* Ulrich et al., PRL 102, 016102, (2009).



